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Exfoliation of a metal–organic framework enabled by post-synthetic cleavage of a dipyridyl dianthracene ligand†

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The synthetic tunability and porosity of two-dimensional (2D) metal–organic frameworks (MOFs) renders them a promising class of materials for ultrathin and nanoscale applications. Conductive 2D MOFs are of particular interest for applications in nanoelectronics, chemo-sensing, and memory storage. However, the lack of covalency along the stacking axis typically leads to poor crystallinity in 2D MOFs, limiting structural analysis and precluding exfoliation. One strategy to improve crystal growth is to increase order along the stacking direction. Here, we demonstrate the synthesis of mechanically exfoliable macroscopic crystals of a 2D zinc MOF by selective dimensional reduction of a 3D zinc MOF bearing a dianthracene (diAn) ligand along the stacking axis. The diAn ligand, a thermally cleavable analogue of 4,4'-bipyridine, is synthesized by the direct functionalization of dianthraldehyde in a novel "dianthracene-first" approach. This work presents a new strategy for the growth of macroscopic crystals of 2D materials while introducing the functionalization of dianthraldehyde as a means to access new stimuli-responsive ligands.

Introduction

Since the isolation and characterization of monolayer graphene as a two-dimensional (2D) semi-metal, the search for other 2D materials that can be exfoliated, studied, and eventually used at the ultrathin limit has captured the attention of chemists, materials scientists, and engineers alike.^{1–12} 2D metal–organic frameworks (MOFs) have distinct properties from traditional 2D materials, particularly in terms of their high porosity and synthetic tunability.^{10–18}

Synthesizing large, exfoliable single crystals of 2D MOFs remains a major challenge, limiting our understanding of their structure and properties, as well as their use at the 2D limit.^{11,17–20} Lack of covalent bonding between the 2D sheets often leads to stacking faults and misalignment of layers along the stacking axis, producing needle-like crystalline morphologies or microcrystalline powders.^{11,18–21} As the crystallinity of these materials decreases, grain boundaries between the crystallites increase, reducing the electrical and thermal conductivity of the bulk material.^{11,18,19,21–23} Highly crystalline material

is therefore crucial in understanding the intrinsic properties, trends, and structure–function relationships of 2D MOFs.^{11,18,19}

There have been numerous attempts to improve the growth of large, exfoliable, single crystals of 2D MOFs.^{18,19,24–27} Besides optimizing synthetic conditions (*i.e.* temperature, solvent, metal source, *etc.*), different methods, including biphasic^{19,27} approaches and the addition of modulators,^{28,29} have been developed to increase control over the kinetics of crystal growth. Modifying the MOF itself by increasing the strength of inter-layer covalent interactions has also been shown to increase crystal size by improving order along the stacking axis.^{18,19,24–26} Additionally, dimensional reduction by post-synthetic ligand insertion or removal^{30–33} has resulted in some successful examples of exfoliable MOFs, leading us to hypothesize that the introduction of a post-synthetically cleavable, covalent link could be effective.

Herein, we introduce a new approach for preparing large, exfoliable crystals of 2D MOFs by exploiting the reversible photodimerization reaction of anthracene (An) to dianthracene (diAn). Linking 2D MOF sheets with diAn ligands creates strong covalent bonds in the stacking direction, enabling the synthesis of large, single crystals. Once the dianthracene-linked 3D MOF has been synthesized, the diAn ligands can be selectively undimerized through post-synthetic annealing (Fig. 1). After annealing, the resulting 2D MOF can be mechanically exfoliated into thin sheets.

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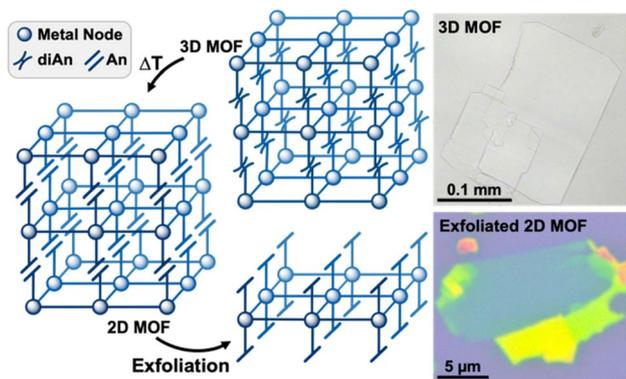


Fig. 1 Generalized pathway from a diAn-linked 3D MOF to an exfoliated, 2D monolayer (left). Optical images of the 3D (top right) and exfoliated 2D MOF (bottom right) produced in this work. The teal region represents 5–6 layers, as measured by atomic force microscopy (AFM).

Results and discussion

The reversible photodimerization of anthracene has only recently been exploited for stimuli-responsive inorganic and materials applications.^{34–37} Although prevalent within polymer chemistry,^{38–42} few 9,9'-functionalized diAn compounds exist as linking ligands within coordination networks (CNs).^{43–52} These examples have exhibited changes in magnetism, luminescence, and photomechanical response upon undimerization and feature diAn as a multi-dimensional ligand (Fig. 2a).^{43–52} Thus, upon undimerization, these frameworks break into molecular species or chains.^{43–52} In order to use diAn to prepare a 2D MOF by dimensional reduction, the diAn ligand must selectively bind along the stacking axis.

4,4'-Bipyridine (bipy) is a commonly used linker in coordination polymers and 3D MOFs,^{13,14} frequently forming networks in which bipy links metal sites along one axis, while anionic ligands link in the other two dimensions.^{53–55} We hypothesized that a 9,9'-functionalized diAn analogue of bipy could enable the desired orientation of the cleavable diAn group in the

stacking direction. In most known examples of 9,9'-functionalized diAn ligands, the diAn group presents considerable steric bulk close to the donor atom(s), limiting the synthesis of MOFs to those that use large cations, such as lanthanides or precious metals, and, rarely, first-row transition metals (Fig. 2a).^{43–52} We targeted the synthesis of a diAn ligand analogue of bipy as a selective linker for 2D sheets with an imine link and methyl spacer to provide more distance between the pyridyl ligands and the sterically bulky diAn core (Fig. 2b).

The preparation of diAn ligands presents a unique synthetic challenge. While syntheses of functionalized anthracene monomers are often straightforward, dimerization must then be achieved either by irradiation of crystalline material or in a highly concentrated solution. Solid state photodimerization requires that the anthracenes crystal pack serendipitously within 4.2 Å and in the correct alignment, with the anthracenes fully overlapped.^{46,56} In solution, the concentration must be high enough so that an excited anthracene can react with a nearby anthracene to form an excimer before decaying.⁵⁷ Functionalized monomers such as those required to produce a diAn bipy analogue are typically much less soluble than more simply substituted anthracenes, precluding solution-phase dimerization.⁵⁷

To bypass this dilemma, we employed a “dianthracene-first” approach by direct functionalization of 9,9'-dianthraldehyde (diAn^{CHO}), which can be prepared from inexpensive 9-anthraldehyde on gram scale (Fig. 2b).⁵⁸ Functionalization of diAn derivatives has been scarcely reported,^{38,39,59,60} with no previous literature reports of diAn^{CHO} derivatization. Reaction conditions must account for the solution phase thermal undimerization of diAn^{CHO}, which occurs within hours above 65 °C, as well as its marginal solubility in most solvents. Therefore, we elected to functionalize diAn^{CHO} with a liquid primary amine, affording high reagent concentrations to overcome the thermal and solubility challenges inherent to diAn^{CHO}. Condensation in neat 3-picolyamine at 60 °C produced the desired pyridine-terminated dimer, di-(*N*-(9-anthracenylmethylene)-3-pyridinmethanamine) (diAn^{CNC-3Py}), in 94.4% yield.

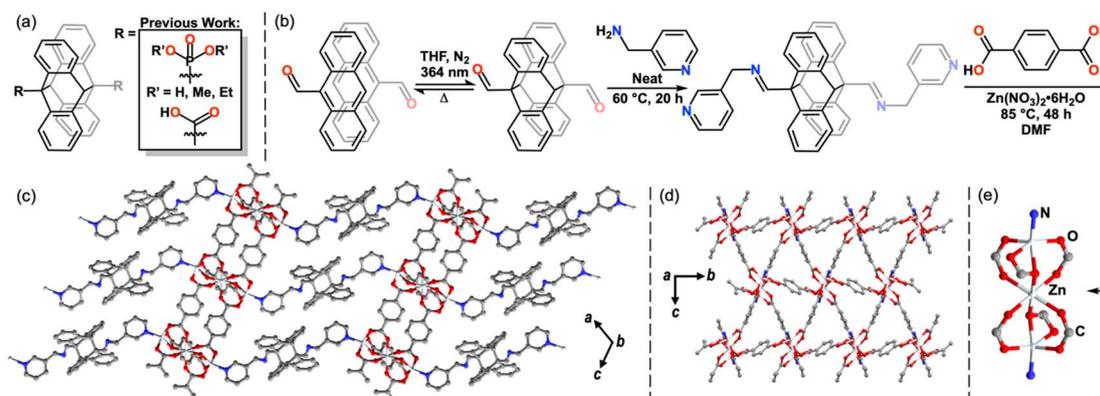


Fig. 2 Previously known 9,9'-functionalized diAn ligands for MOFs and CNs (a). “Dianthracene-first” synthesis of the diAn^{CNC-3Py} ligand (b). The crystal structure of **1**, depicting the view along the stacking direction (c), across the 2D Zn₃BDC₃ sheets within the 3D structure, where the diAn ligand has been reduced to a single nitrogen atom for clarity (d), and the tri-zinc node (e). All hydrogen atoms and DMF molecules have been omitted for clarity.



With the pyridyl-terminated diAn in hand, we sought to generate a layered MOF incorporating this ditopic, neutral linker. One such platform is the $\text{Zn}_3\text{BDC}_3\text{L}_2$ lattice, where BDC = 1,4-benzenedicarboxylic acid, first reported by Hubberstey, Schröder and coworkers in 2005.⁶¹ This general motif features 2D Zn-carboxylate sheets capped or linked by neutral mono- and ditopic ligands to produce 2- and 3D structures.^{62–65} An example of a $\text{Zn}_3\text{BDC}_3\text{L}_2$ framework from Yu and coworkers⁶⁵ features an apical pyridine, while a 3D analogue from Zheng and coworkers features a bridging bis(imidazole) spacer.⁶³ The ability of the $\text{Zn}_3\text{BDC}_3\text{L}_2$ motif to bind neutral, nitrogen-based capping ligands and the tolerance of the overall structure toward different dimensionalities make this an attractive platform in which to incorporate diAn^{CNC-3Py}. Indeed, solvothermal synthesis in *N,N*-dimethylformamide (DMF) at 85 °C using a 1 : 1 : 4 ratio of $\text{Zn}(\text{NO}_3)_2 \cdot 6\text{H}_2\text{O}$: diAn^{CNC-3Py} : BDC yields a crystalline 3D MOF, $\text{Zn}_3\text{BDC}_3\text{diAn}^{\text{CNC-3Py}}$ (**1**), with two lattice DMF molecules per formula unit in the $P2_1/c$ space group (Fig. 2c–e). The clear, colorless plates were characterized by single crystal X-ray diffraction (SCXRD) and the bulk material was confirmed to be uniform by powder X-ray diffraction (PXRD) and optical microscopy (Fig. 3g, S19, S26 and S27†). The secondary building unit (SBU) of **1** consists of three zinc atoms and six BDC molecules (Fig. 2e). The central zinc atom is pseudo-octahedral, bound to two monoatomic and four *syn-syn* bidentate bridging oxygen atoms of six discrete BDC carboxylates. The outer zinc atoms, related by symmetry, are distorted square pyramidal in coordination geometry. Each is bound to a terminal pyridine moiety of diAn^{CNC-3Py} and four oxygen atoms from three BDC carboxylates. The BDC ligands connect individual SBUs, forming a 2D sheet (Fig. 2d). These 2D Zn_3BDC_3 sheets are linked by diAn^{CNC-3Py}, resulting in a 3D MOF with similar connectivity to the $\text{Zn}_3\text{BDC}_3(1,2\text{-bis}(2\text{-(1H-imidazol-1-yl)ethoxy)ethane})_2$ framework, which also bears a ditopic, N-donor ligand in the stacking dimension (Fig. 2c).⁶³

The connection of 2D Zn_3BDC_3 sheets by diAn^{CNC-3Py} within the 3D lattice makes **1** an excellent candidate for dimensional reduction into an exfoliatable 2D material. Photochemical and thermal cleavage of diAn is well established, with several diAn-bridged MOFs known to undimerize into lower-dimensional compounds (3D to 1D or 3D to 0D molecules).^{43,46} To determine suitable annealing conditions for **1**, we turned to thermogravimetric analysis (TGA) and differential scanning calorimetry (DSC). The TGA curve for **1** revealed a mass loss of 14.3% upon heating to 190 °C, broadly consistent with the loss of the two solvent molecules (calculated $112.51 \text{ g mol}^{-1}$, 1.54 equiv. DMF) from within the lattice (Fig. S6†). No further mass loss was observed until the onset of material degradation at 300 °C. DSC analysis of **1** revealed an exothermic peak centered at 210 °C, consistent with undimerization of the diAn core (Fig. 3a).⁴⁵ The DSC curve for the free diAn^{CNC-3Py} ligand features a sharp peak at 196 °C; the shift in this feature to higher temperature in **1** is likely a consequence of structural confinement within the 3D lattice as has been observed for other diAn-linked MOFs.^{45–47,49,51}

Based on the DSC of **1**, pristine crystals were annealed at 210 °C. After 2 min at 210 °C, the once-colorless crystals began

to turn yellow while retaining their overall size and shape (Fig. 3b). The crystals continued to turn a darker yellow-orange color until annealed for about 10 minutes, after which the color remained constant. The yellow color is consistent with conversion of diAn^{CNC-3Py} ligands to their monomeric form, and thus the generation of the 2D MOF, $\text{Zn}_3\text{BDC}_3\text{An}^{\text{CNC-3Py}_2}$ (**2**). This is supported by an analogous annealing experiment, where free diAn^{CNC-3Py} was heated to 196 °C for 10 min, revealing complete transformation of diAn^{CNC-3Py} to the corresponding monomer, An^{CNC-3Py}, by ¹H nuclear magnetic resonance (NMR) spectroscopy (Fig. S4†).

Solid-state UV-vis spectroscopy was also used to compare the dimer and monomer ligands to MOFs **1** and **2** (Fig. 3c). The MOF spectra have similar features to their ligand counterparts. The normalized spectra of diAn^{CNC-3Py} and **1** show strong absorbance features in the UV region at approximately 300 nm and 400 nm, while the normalized spectra of An^{CNC-3Py} and **2** show strong absorbance features at 460 nm, corresponding to their yellow-orange color. The DSC data obtained for a sample of **1** annealed for 10 min at 210 °C lacks any exothermic feature, further confirming complete undimerization of the diAn^{CNC-3Py} ligand (Fig. 3a). This relationship between DSC peak temperature, annealing time, and complete undimerization is consistent with that observed for other diAn-linked MOFs.^{45–47,50,51} The TGA curve for **2** reveals little mass loss until the onset of material degradation at 310 °C, indicating that the DMF molecules trapped in the lattice of **1** are liberated upon annealing (Fig. S6†).

Characterization of **2** by SCXRD was attempted, however, annealing decreases the crystal domain size, prohibiting collection of an SCXRD structure. This is also observed through the line broadening of PXRD traces as the sample is annealed (Fig. 3g, S26, and S27†). We instead turned to microcrystal electron diffraction (MicroED), which allows for structural determination of significantly smaller crystal domains. MicroED analysis of crystals of **1** annealed for 3 min at 210 °C yields the fully undimerized, 2D MOF crystal structure in the $P2_1/c$ space group with no solvent in the lattice (Fig. 3d–f). The only substantive difference between the structures of **1** and **2** is in the stacking direction. In **2**, the An^{CNC-3Py} ligands are stacked so that the anthracene of one layer is next to the pyridine of the adjacent layer, resulting in a stacking distance approximately 0.5 nm shorter between the 2D layers (Fig. 3d). The 2D Zn_3BDC_3 sheets maintain the same structural connectivity as in the pristine 3D MOF, **1**, but the SBUs of **2** are now slightly offset from the SBUs of adjacent layers (Fig. 2e and S30†). Attempts to independently synthesize **2** from the monomeric ligand, An^{CNC-3Py}, were unsuccessful and consistently produced the water-capped analogue.⁶² This highlights the importance of diAn^{CNC-3Py} in generating **2**.

While diAn-linked MOFs that undergo 3D to 1D or 3D to 0D dimensional reduction often crack upon thermal annealing, we note that annealed samples of **1** are identical in appearance to their pristine state aside from the yellow color arising from the anthracene monomers, with no new cracks or features observable by optical microscopy (Fig. 3b). We propose that this greater morphological fidelity arises from the decreased strain



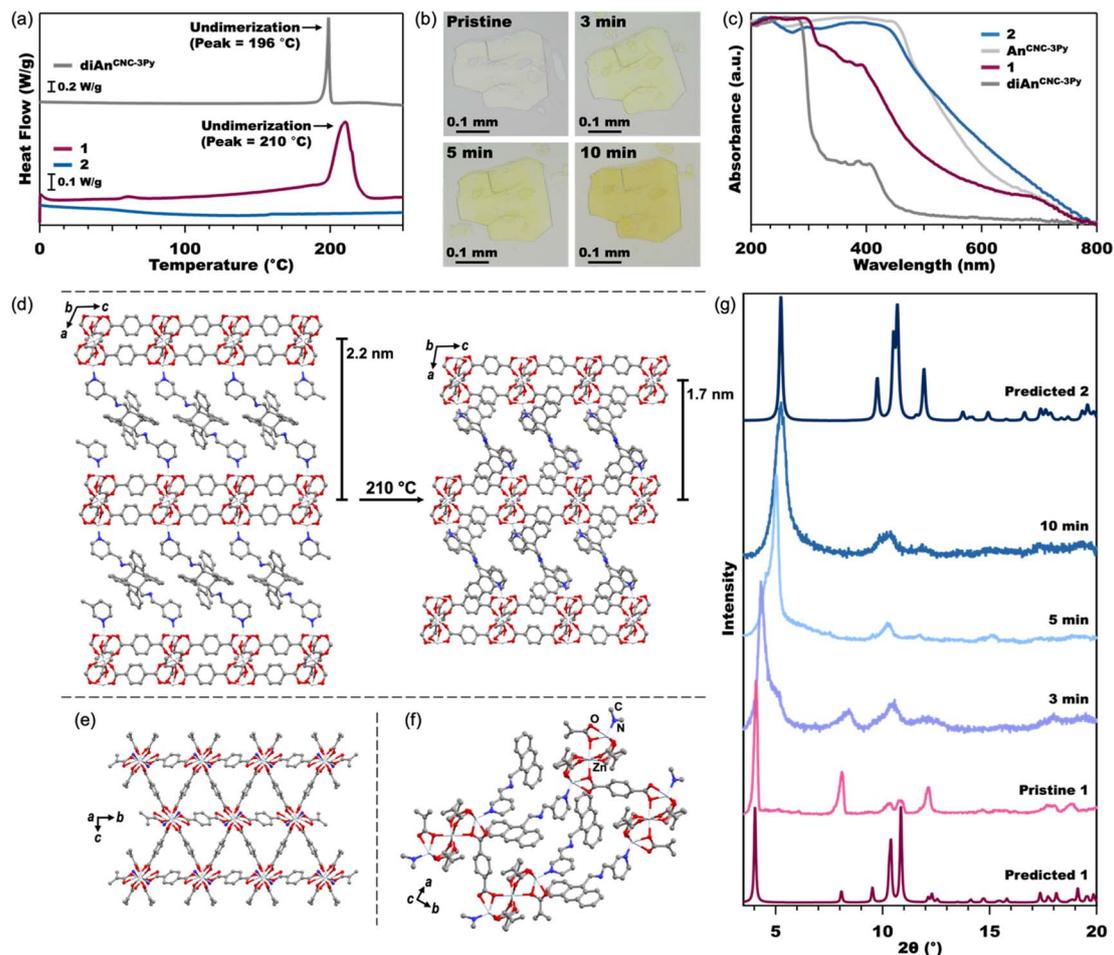


Fig. 3 DSC (a) of the diAn^{CNC-3Py} ligand and MOFs 1 and 2 from 0–250 °C (see Fig. S7† for full data plot). Optical microscope images (b) of pristine crystals of 1 and crystals annealed at 210 °C. Normalized solid-state UV-vis spectra (c) of the diAn^{CNC-3Py} and An^{CNC-3Py} ligands and MOFs 1 and 2. Crystal structures (d) of 1 (left) and 2 (right) showing compression of the 2D Zn₃BDC₃ sheets upon undimerization of diAn. A view across the 2D Zn₃BDC₃ sheets of 2, (e) where the An ligand has been reduced to a single nitrogen atom for clarity. A close-up view of the stacking between An ligands in 2 (f). All hydrogen atoms have been omitted for clarity. PXRD (g) of pristine crystals of 1, crystals annealed at 210 °C, and predicted spectra from the SCXRD and MicroED structures of 1 and 2, respectively.

induced by undimerization along one axis compared to that induced by undimerization along two or three axes. The thermal annealing of 1 produces a rapid phase change in the PXRD pattern of the material (Fig. 3g). The features at 4.2° and 8.2° in 1, which both correspond to reflections along the stacking axis, *a*, increase to 5.3° and 10.4° as the MOF is annealed. Although the MicroED structure of 2 was collected on crystals annealed for 3 min, we note that this structure does not feature any disorder corresponding to a mixture of phases between 1 and 2 as is demonstrated in the measured PXRD at 3 min (Fig. 3g). Therefore, although bulk conversion of 1 to 2 does not occur until 10 min at 210 °C, we conclude that the domains analyzed by MicroED were fully undimerized in the short annealing time.

The layered nature of both 1 and 2 is clear from scanning electron microscopy (SEM) and indicates that 2 is a suitable material for exfoliation (Fig. 4a, b, S13, and S14†). We note that, in our hands, the Py-capped analogue⁶⁵ is similarly produced as plate-like crystals which can be mechanically exfoliated (Fig. S24†). Therefore, annealing conditions were optimized for

mechanical exfoliation by the Scotch tape method (Fig. S22†). Exfoliation of crystals annealed for longer times at lower temperatures produced larger exfoliated flakes than those annealed at 210 °C. Thus, crystals of 1 were annealed at 160 °C for 18 h, which shows complete conversion to 2 by PXRD (Fig. S26†). Mechanical exfoliation of 2 onto Si/SiO₂ substrates produced atomically flat flakes as thin as 4 nm (determined by AFM, Fig. 4, S17, and S18†). A representative 10 nm flake is shown in Fig. 4c–e. The height of a single layer of 2 is expected to be ~1.7 nm according to the MicroED crystal structure of 2, with a 10 nm sample representing roughly five or six layers. The average root mean squared (RMS) roughness of a single layer sampled from 16 flakes is 0.471 nm (standard deviation = 0.179 nm) (Fig. S18 and Table S1†).

Confirmation that exfoliated flakes were indeed crystals of 2 was gained from optical photothermal infrared (O-PTIR) spectroscopy, which allows for the acquisition of spatially-resolved vibrational spectra of thin samples. The O-PTIR spectra of exfoliated crystals were found to be in excellent agreement with



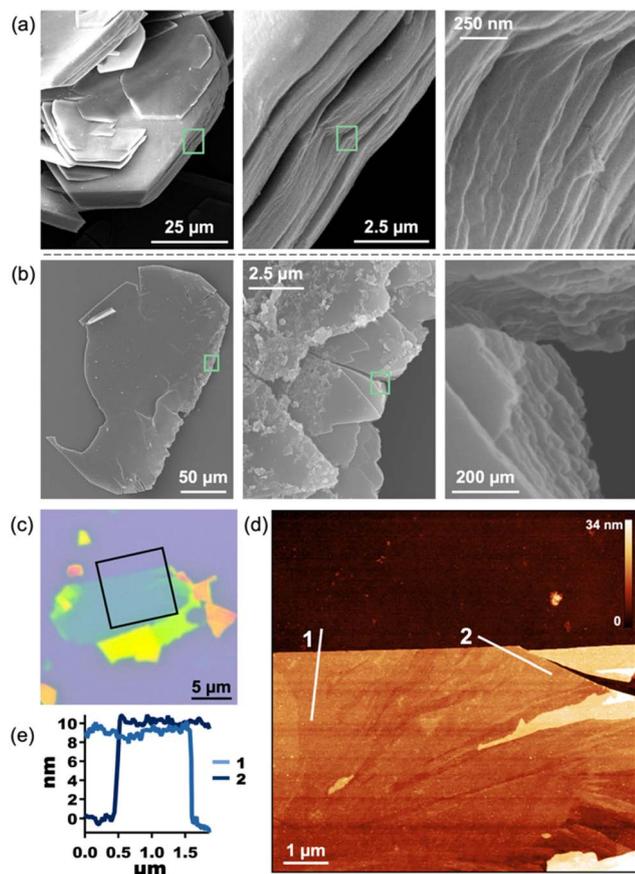


Fig. 4 SEM of MOFs 1 (a) and 2 (b) with progressively magnified images (left to right) showing the layers of the crystals' edges. Optical image (c) of an exfoliated flake of 2 on a Si/SiO₂ wafer, its AFM topography map (d), and height profile (e).

those of bulk annealed 2, indicating that the material remained unchanged after exfoliation (Fig. S11 and S12[†]). Additional evidence of material integrity upon exfoliation was found by X-ray Photoelectron Spectroscopy (XPS), which revealed the expected elemental composition of the exfoliated MOF (Fig. S16[†]). While pristine crystals of 1 cannot be exfoliated at all, 2 can be mechanically exfoliated to few-layer samples, demonstrating the first example of the conversion of a dianthracene-based 3D framework into exfoliatable 2D sheets.

Conclusions

The “dianthracene-first” method of direct functionalization of diAn^{CHO} allowed us to prepare a new, neutral, minimally sterically encumbered diAn analogue of 4,4'-bipyridine (bipy), which in turn enabled the preparation of a 3D Zn MOF with cleavable diAn links along only one axis. 3D MOFs and CNs commonly feature bipy as a linker between 2D sheets, making our approach promising for application to diverse molecular materials. MOF 1 can be thought of as a masked 2D material that can be grown with complete control over structure in the stacking direction, giving rise to large, single crystals with a favorable aspect ratio for exfoliation. Annealing releases the

diAn linkage, achieving dimensional reduction to the 2D, mechanically exfoliatable form without loss of sample integrity or size. Additionally, in magnetic and/or conductive MOFs, the compression of 2D sheets from the undimerization of diAn would be expected to modify the coupling or electron transport between the layers. Ongoing work in our group seeks to harness this strategy to both engineer specific interlayer alignments in 2D molecular materials, as well as to access large crystals of magnetic and/or electrically conductive 2D MOFs.

Data availability

Data for this article are available at <https://doi.org/10.1039/D4SC03524K>. The data supporting this article (detailed experimental and synthetic methods and characterization, including NMR, TGA, DSC, ATR-FTIR, O-PTIR, SEM, XPS, AFM, optical images, exfoliation techniques, XRD, MicroED data, and crystallographic tables) have been included as part of the ESI.[†] Crystallographic data for 1 and 2 has been deposited at the CCDC under 2342280 (1) and 2356228 (2) and can be obtained from <https://www.ccdc.cam.ac.uk/>.

Author contributions

M. E. L. and A. K. B. conceived and planned the experiments. M. E. L. synthesized all complexes and collected all data except for SEM, XPS, DSC, TGA, MicroED, and O-PTIR. E. S. performed SEM, DSC and TGA experiments. B. Q. M. collected MicroED data and solved and refined the MicroED crystal structure. M. J. B. collected O-PTIR data and contributed O-PTIR-related text. C. M. D. conceived of O-PTIR experimental setup, interpreted O-PTIR, and contributed to manuscript editing. M. E. L., E. S., and A. K. B. contributed to the writing of the manuscript.

Conflicts of interest

There are no conflicts to declare.

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